

The Silicon Vertex Detector of the Belle II Experiment

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Outline

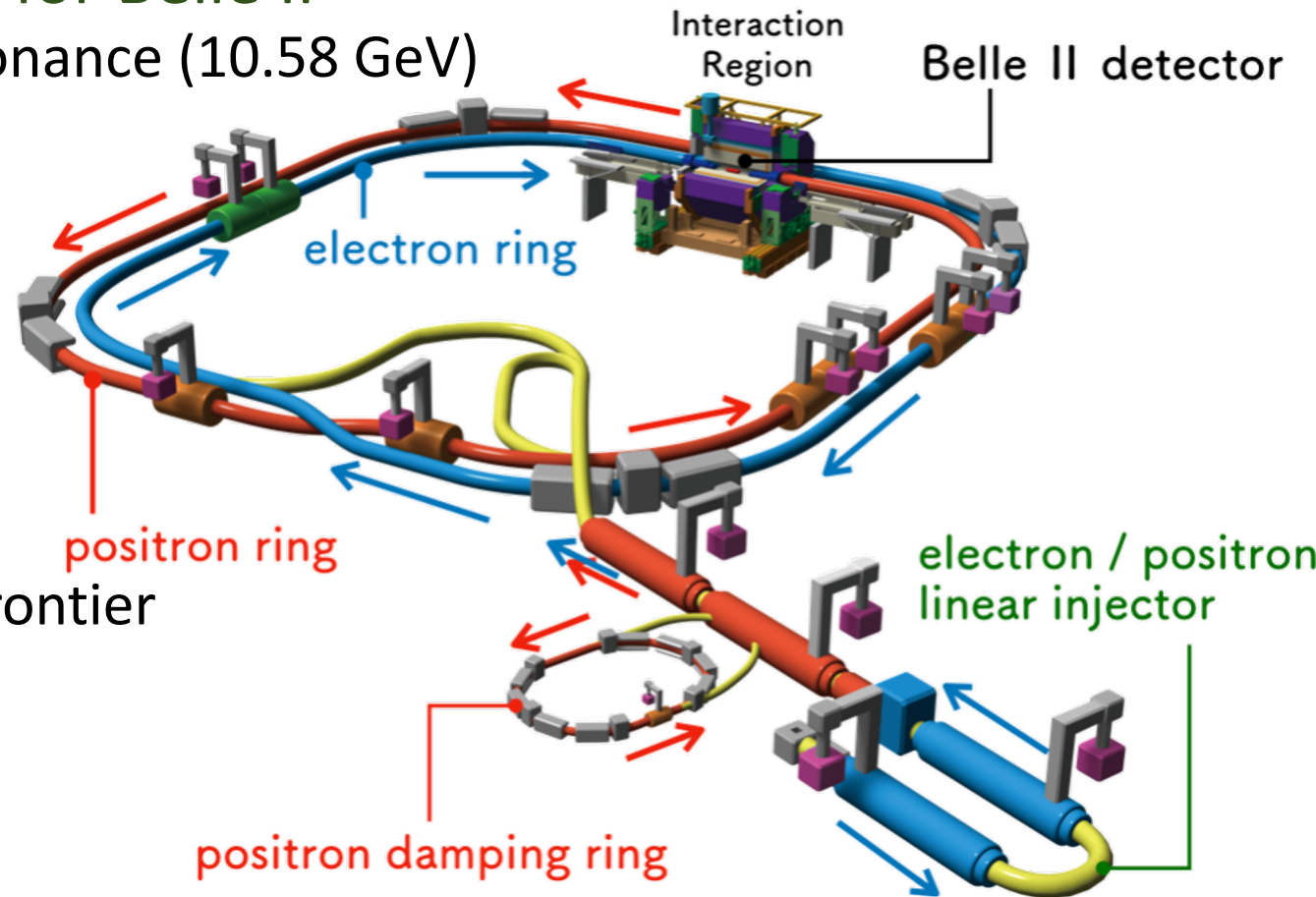
- ◆ Introduction
- ◆ Operation & Performance
- ◆ Beam background & Radiation effect
- ◆ Conclusions

Introduction

Belle II/SuperKEKB

◆ SuperKEKB: dedicated accelerator for Belle II

- Asymmetric e^+e^- collisions at $\Upsilon(4S)$ resonance (10.58 GeV)
- Target integrated luminosity: 50 ab^{-1}
- Target instantaneous luminosity: $\sim 6 \times 10^{35} \text{ cm}^{-2}\text{s}^{-1}$
- Current record: $3.1 \times 10^{34} \text{ cm}^{-2}\text{s}^{-1}$



◆ Belle II

- New physics search at the luminosity frontier
 - Accumulated 213 fb^{-1} data
 - Essentials for physics programs:
 - Precise determination of decay vertices
 - Low momentum tracking
 - Good particle identification
- Vertex Detector plays an important role

Belle II Vertex Detector

◆ Requirements

- Better vertex resolution than Belle to compensate reduced Lorentz boost
 - improved point resolution/reduced inner radius/lower material
- Operate in high background environment
 - Hit rate: 3 MHz/cm² @ SVD layer-3
- Radiation hard
 - 0.2 Mrad/yr. @ SVD layer-3

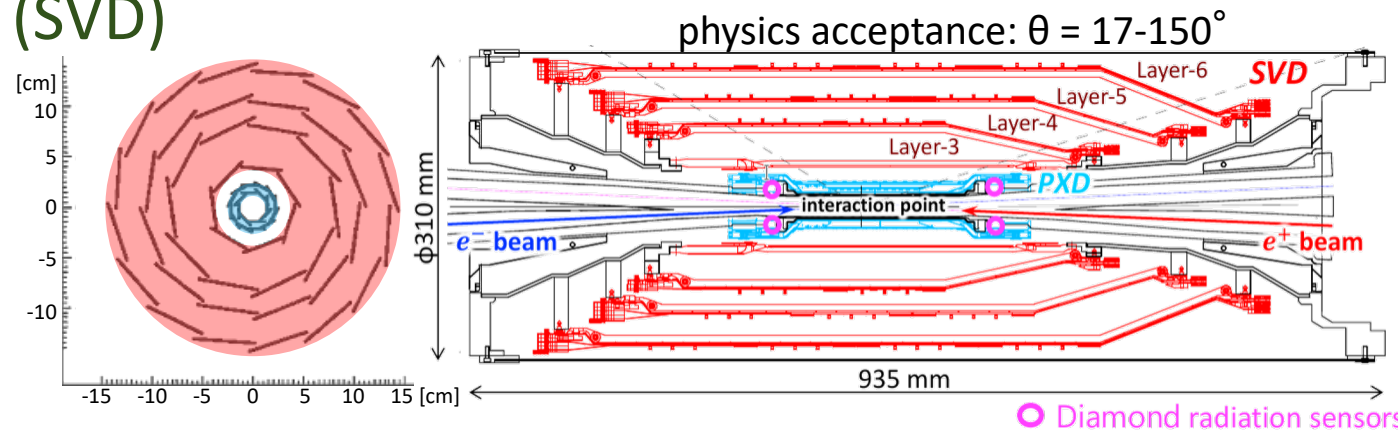
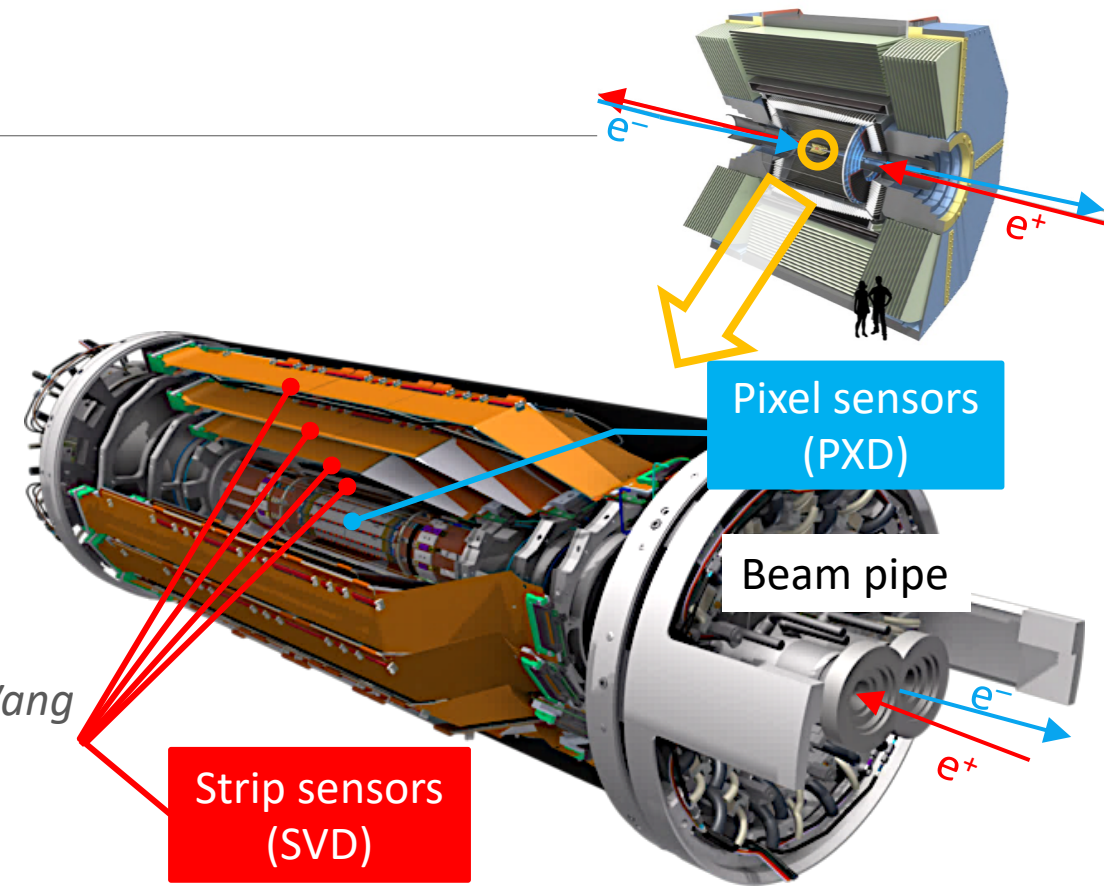
◆ Layers-1-2: Pixel Detector (PXD) → talk by Boqun Wang

- DEPFET pixel sensors
- Innermost layer 1.4 cm from interaction point

◆ Layers-3-6: Silicon Vertex Detector (SVD)

◆ Diamond sensors

- For radiation monitor and beam abort



Belle II Silicon Vertex Detector (SVD)

◆ Layer-3-6: Silicon Vertex Detector (SVD)

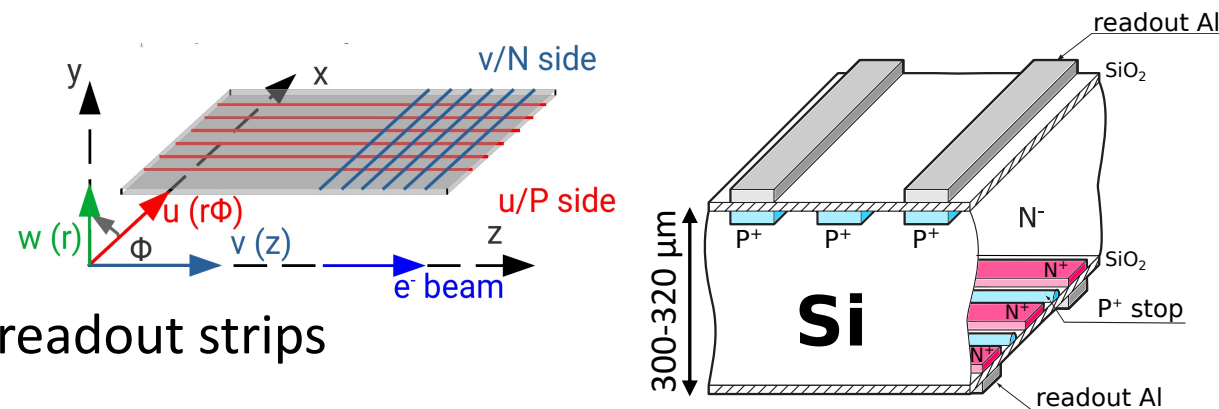
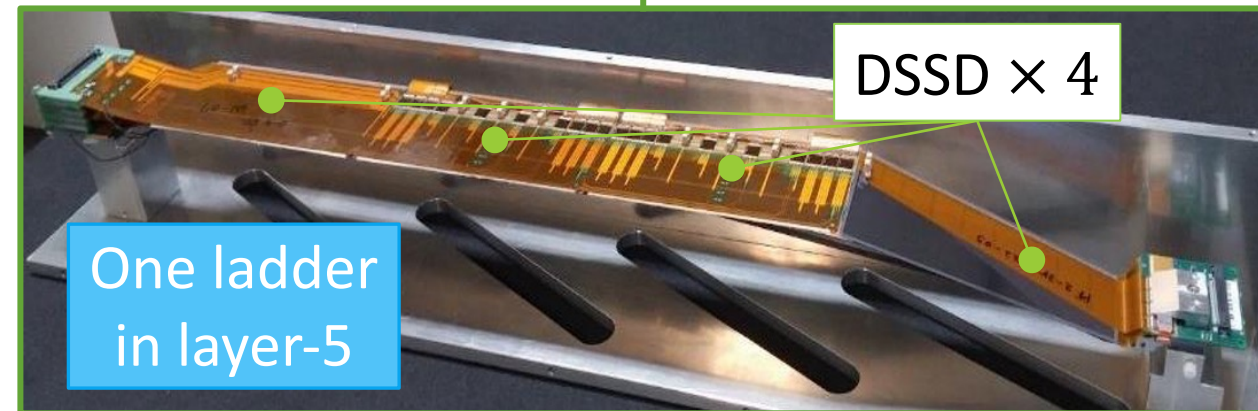
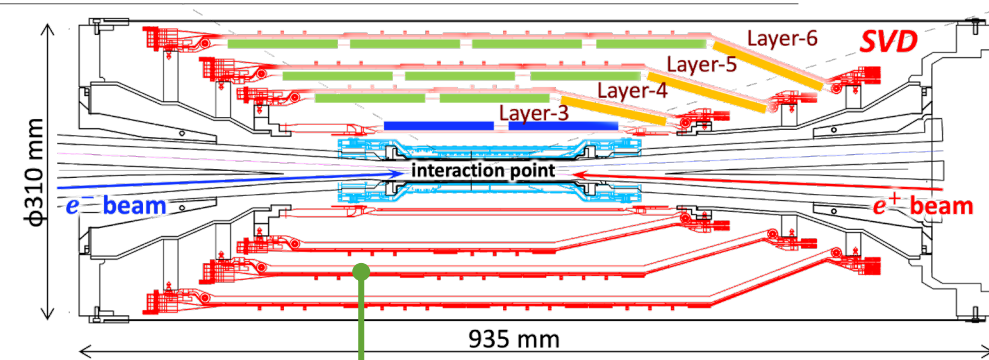
- Double-sided Si strip detectors (DSSDs)
- Low material budget: 0.7% X_0 per layer

◆ SVD Roles

- Extrapolate tracks to PXD
 - essential for reconstruction of decay vertices
 - PXD region of interest for data reduction
- Stand-alone tracking for low p_T tracks
- Precise vertexing of K_S
- PID with dE/dx

◆ DSSDs

- Provide 2-D spatial information
- Strips are AC-coupled to n-type substrate
- Fully depleted at 20-60 V, operated at 100 V
- Total: 172 sensors = 1.2 m² sensor area = 224k readout strips



Belle II Silicon Vertex Detector (SVD)

◆ Layer-3-6: Silicon Vertex Detector (SVD)

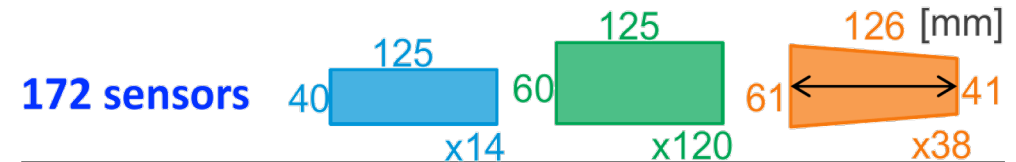
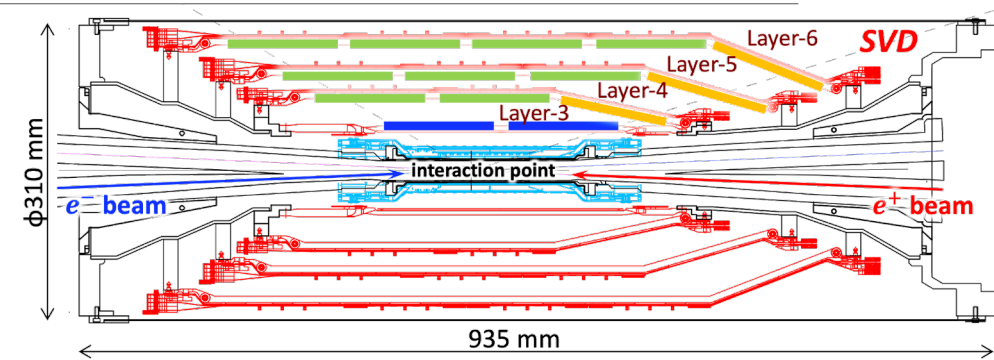
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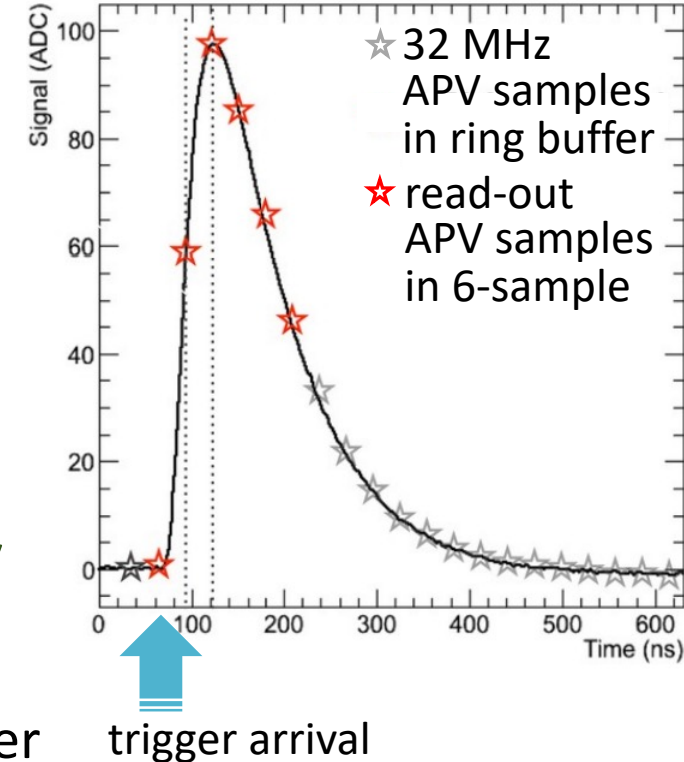


	Small	Large	Trapezoidal
# of p-strips*	768	768	768
p-strip pitch*	50 μ m	75 μ m	50-75 μ m
# of n-strips*	768	512	512
n-strip pitch*	160 μ m	240 μ m	240 μ m
thickness	320 μ m	320 μ m	300 μ m
manufacturer	HPK		Micron

*readout strips – one floating strip on both sides

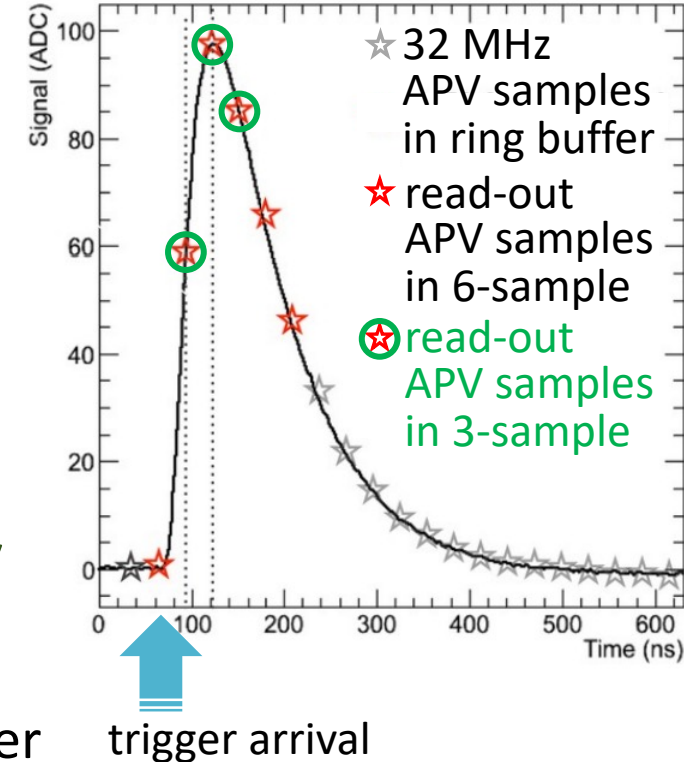
Front-end ASIC: APV25

- Originally developed for CMS silicon tracker
- Fast: 50 ns shaping times
- Radiation hard: > 100 Mrad
- Power consumption: 0.4 W/chip (700 W in total)
- 128 channel inputs per chip
- Operated in “multi-peak” mode @ ~32 MHz
 - Bunch-crossing frequency ~8*32 MHz, clock not synchronous with them as in CMS
 - 6 subsequent samples read-out
- ◆ **3/6-mixed acquisition mode prepared for higher luminosity**
 - To reduce background occupancy, trigger dead-time and data-size
 - Half time-window, half FIFO usage and half hit-information in 3-sample
 - Switching sampling number according to the timing precision of trigger
 - The functionality already implemented in the real setup and confirmed to work
 - few hours of physics data-taking was smooth
 - Performance study needed before moving to 3/6-mixed mode
 - Hit efficiency is the first step → slide 16
 - To be checked: position resolution, dE/dx, hit-time



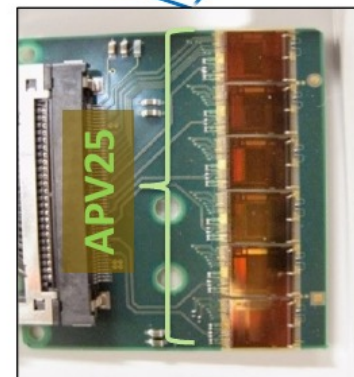
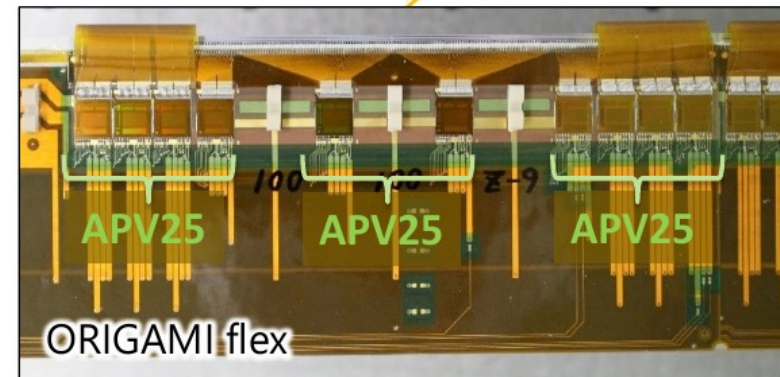
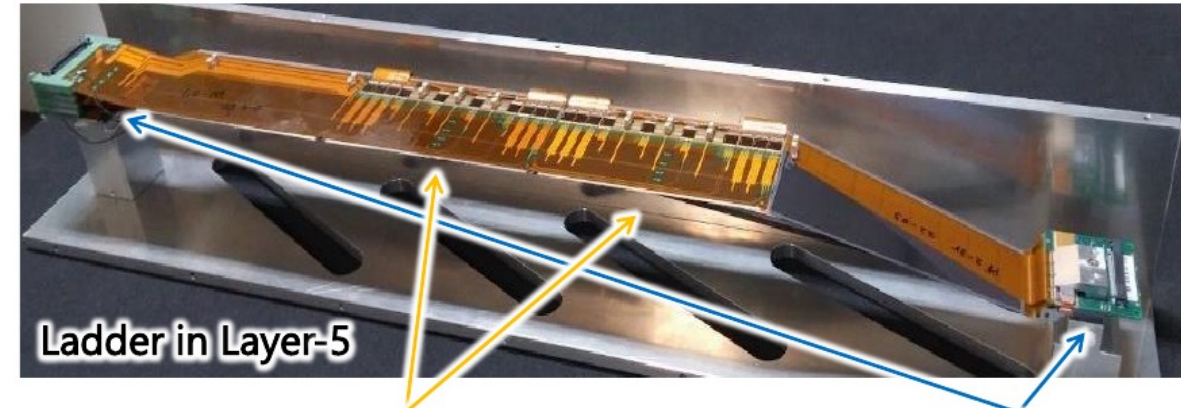
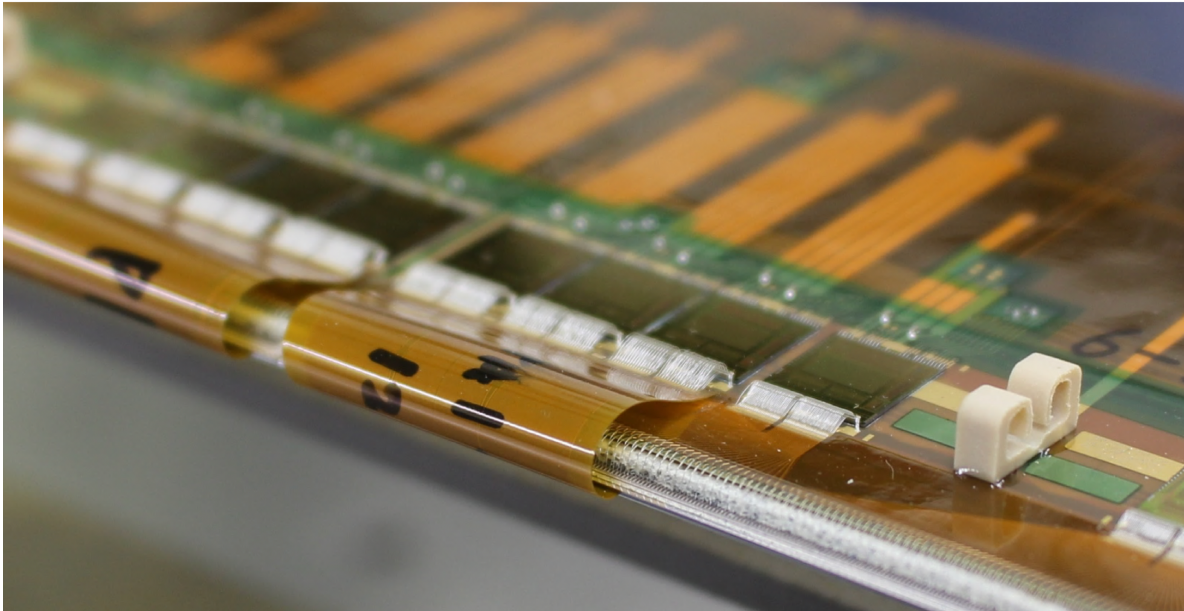
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Origami chip on sensor concept

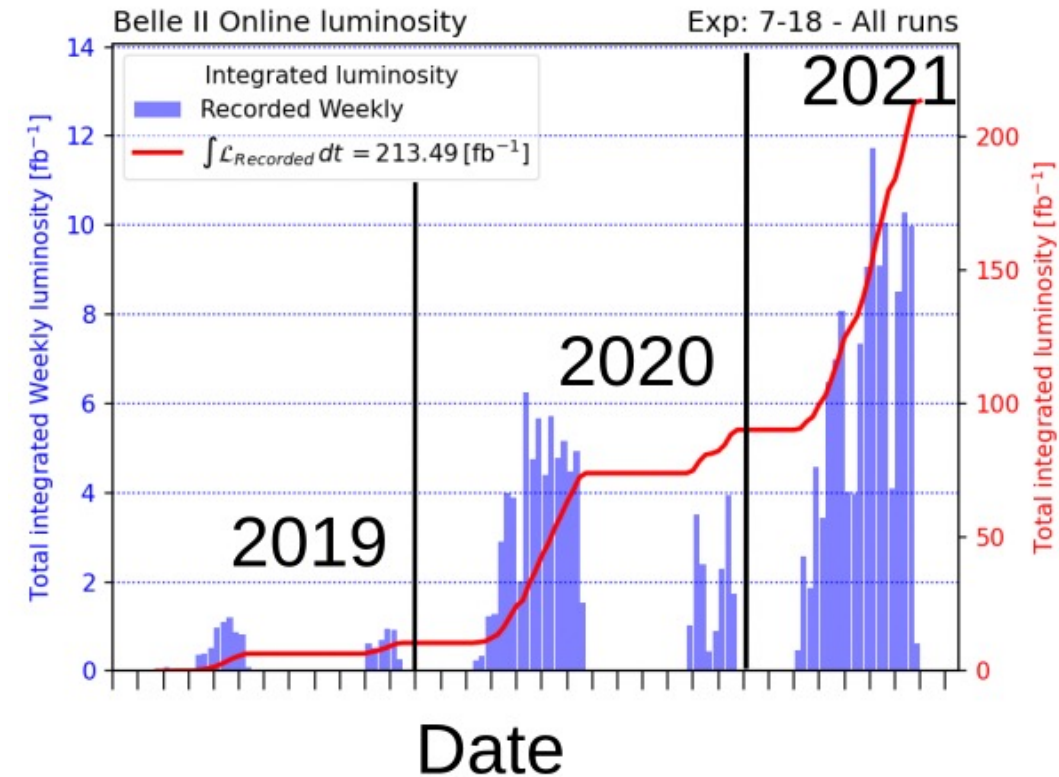
- ◆ Readout chips directly on each middle sensor
 - Shorter signal propagation length (smaller capacitance and noise)
 - Thinned to 100 μm to reduce material budget
 - Wrapped flex to read both sides from the same side
 - Cool only one side with bi-phase $-20\text{ }^{\circ}\text{C}$ CO_2



Operation & Performance

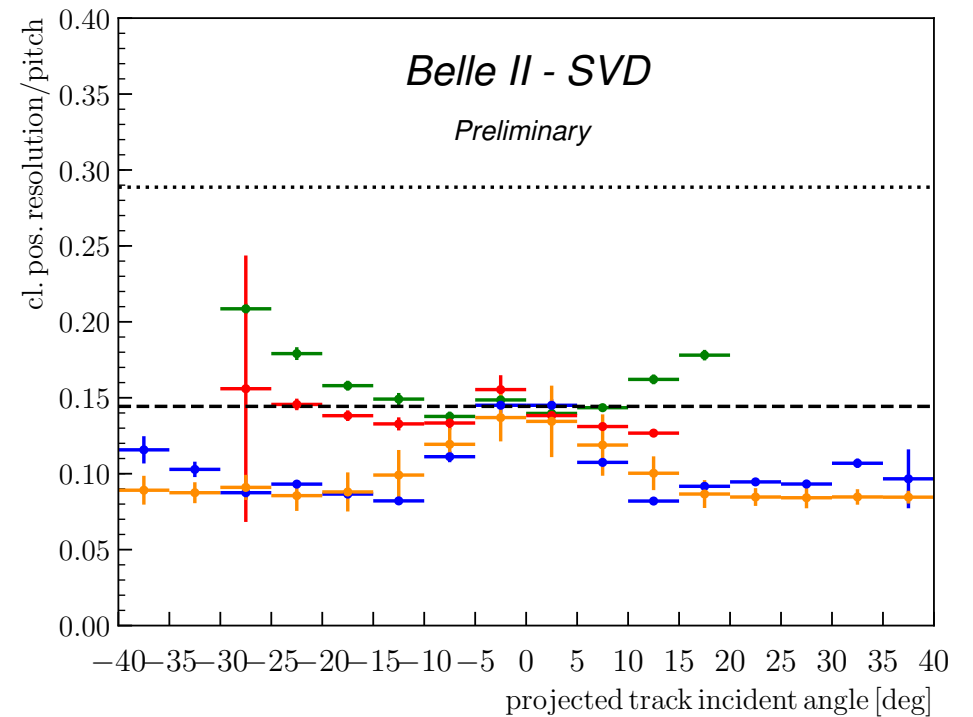
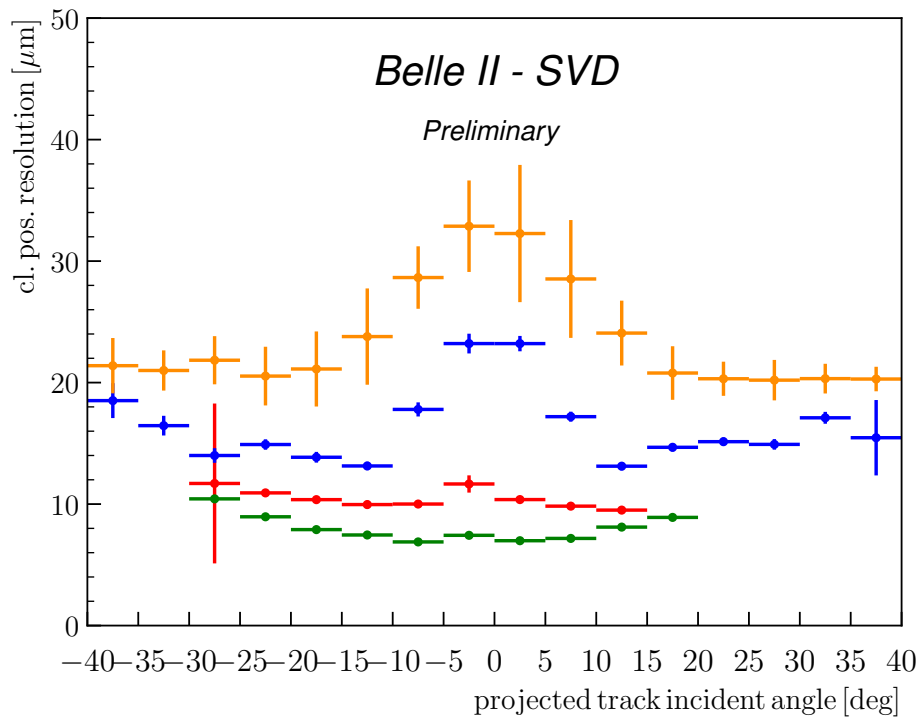
Operational experience

- ◆ SVD installed in 2018, operated since 2019
- ◆ Reliable and smooth operation without major problems
 - Total fraction of masked strips $\sim 1\%$
 - One APV25 chip disabled in spring 2019 (out of 1748)
→ fixed by cable reconnection in summer 2019
- ◆ Excellent detector performance
 - already shown at [Vertex 2020](#)
 - Hit efficiency stably $> 99\%$ in most of the sensors
 - Reasonable cluster charge distribution
 - u/P side: agrees with MIP considering uncertainty in calibration
 - v/N side: 10-30% due to large pitch and floating strip
 - Very good SNR (most probable value: 13-30)
 - updated simulation better agrees with data
→ YSF talk by Mateusz Kaleta



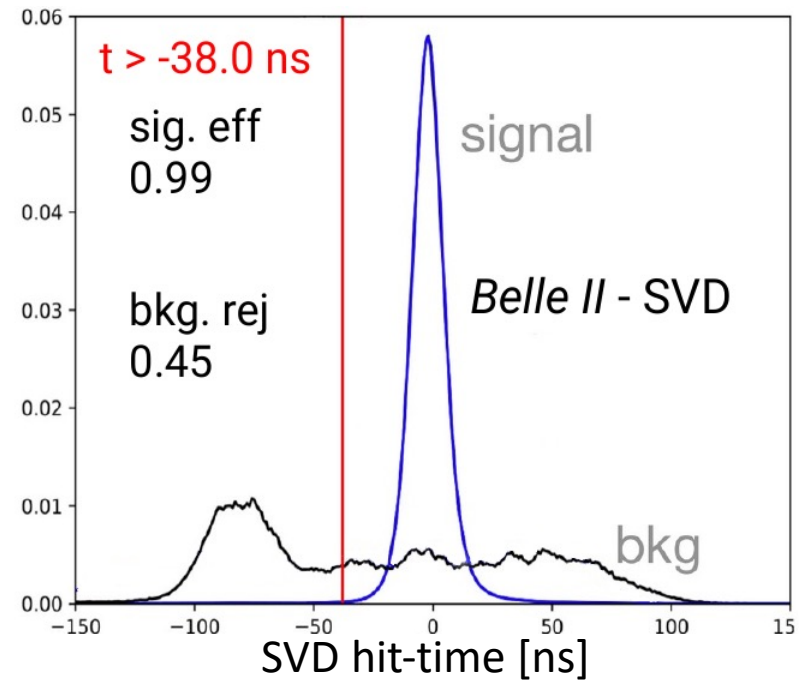
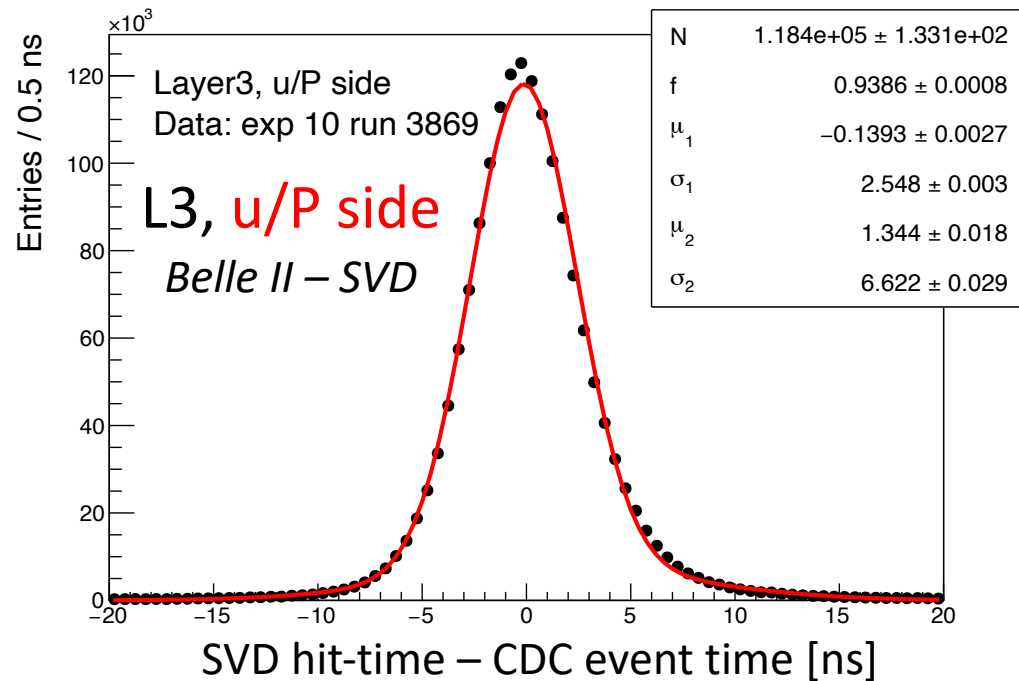
Cluster position resolution → YSF talk by Robin Leboucher

- ◆ Preliminary cluster position resolution measured on $e^+e^- \rightarrow \mu^+\mu^-$ data
 - Estimated from the residual of the cluster position with respect to the track (unbiased)
 - Effect of the track extrapolation error subtracted
 - Excellent position resolution in agreement with the expectations from the pitch
 - Still room for improvement for the u/P side (work ongoing)



Hit-time resolution

- ◆ Excellent hit-time resolution with respect to event time
 - Event time estimated by central drift chamber (CDC) outside of SVD
 - (~ 2.9 ns u/P, ~ 2.4 ns v/N)
- ◆ Possible to efficiently reject off-time background hits
 - Will be used for higher luminosity and background levels



3-sample acquisition mode

◆ Performance

- Ideal 3 samples provide enough information as 6 samples

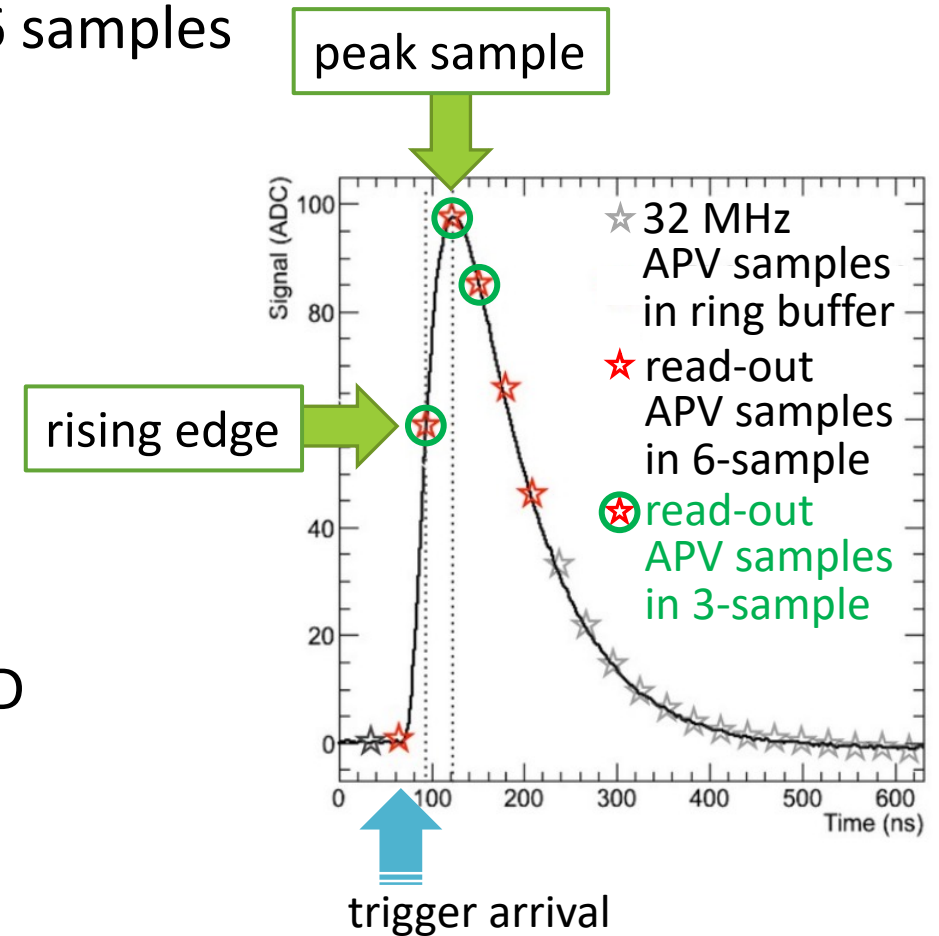
- amplitude – peak ADC sample
- hit-time – rising edge of the waveform

- Degrades if the trigger timing is largely shifted

- CDC event time is a good estimator

◆ 1st step: relative hit efficiency

- $(\text{hit efficiency in 3-sample}) / (\sim \text{in 6-sample})$
- Emulate 3-sample mode offline
- Efficiency based on track using CDC, SVD and PXD
- Relative efficiency > 99.9% for trigger timing shift within ± 30 ns
 - almost a whole clock-cycle



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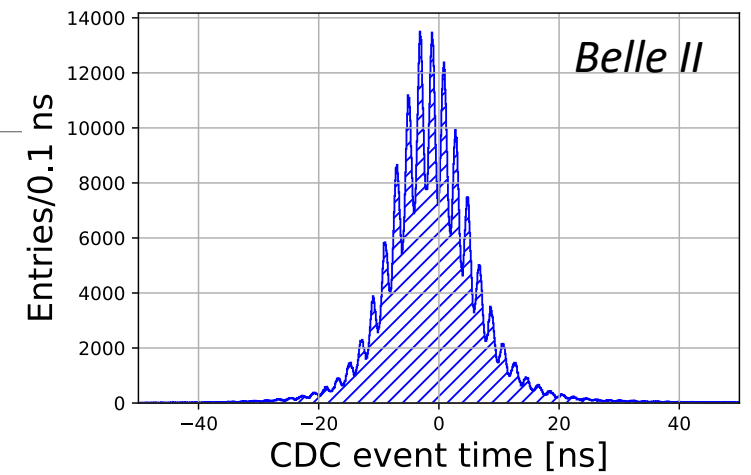
■ (hit efficiency in 3-sample)/(~ in 6-sample)

■ Emulate 3-sample mode offline

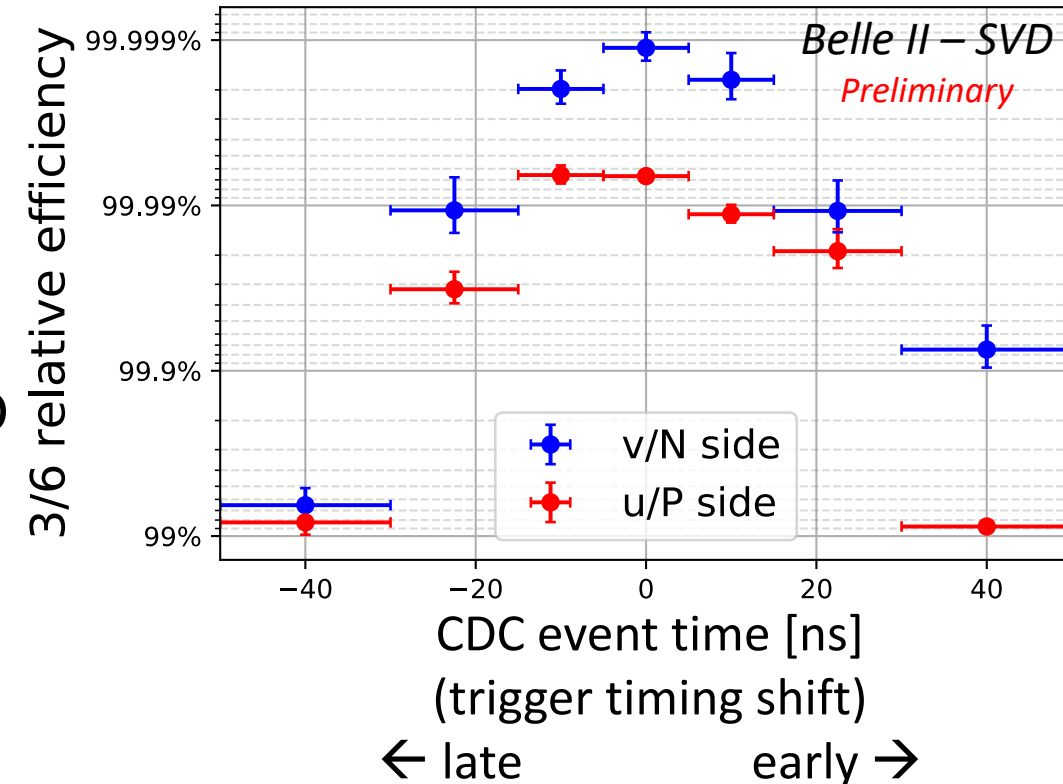
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all sensors combined



Beam background & Radiation effect

Beam background and hit occupancy

◆ Beam background increases SVD hit occupancy which degrades tracking performance

■ Present occupancy limit in layer-3: ~ 3%

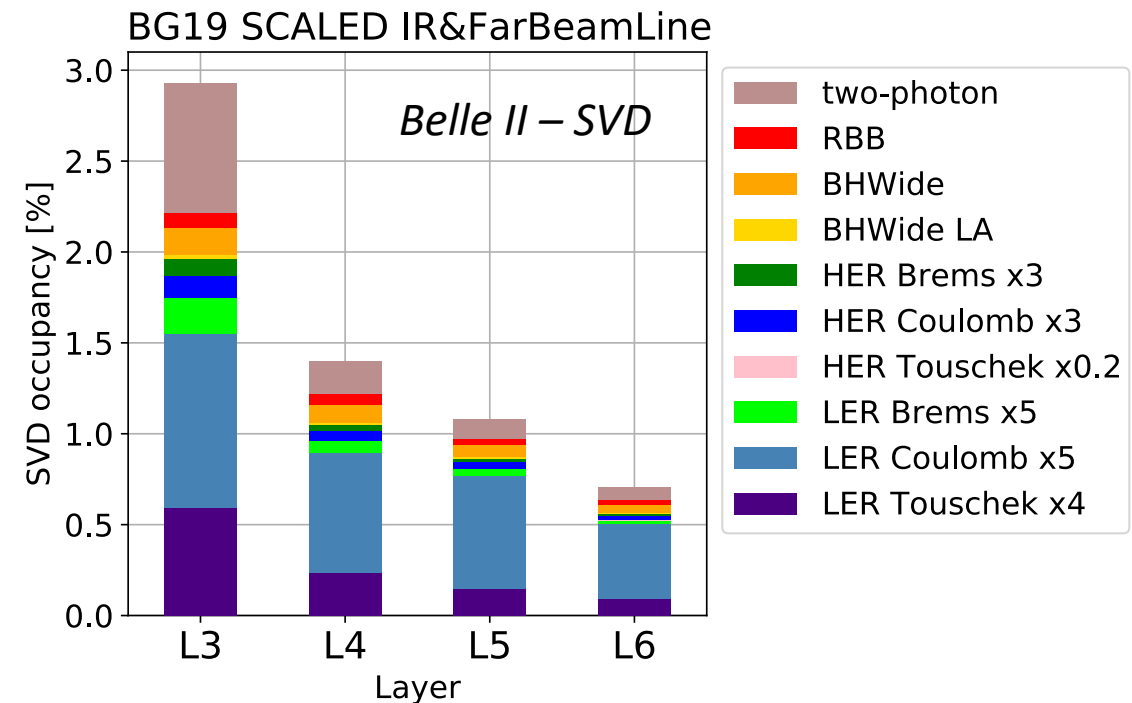
- will be loosened to $\times 2$ using hit-time to reject background

■ With current luminosity, average hit occupancy in layer-3 is well under control ($< 0.5\%$)

■ Projection of hit occupancy at $L = 8 \times 10^{35} \text{ cm}^{-2} \text{ s}^{-1}$ is about 3% in layer-3

- estimated by scaling MC with data/MC ratio
- correspond to dose of $\sim 0.2 \text{ Mrad/smy}$
 - = 1-MeV neutron fluence of $\sim 5 \times 10^{11} \text{ n}_{\text{eq}}/\text{cm}^2/\text{smy}$
 - smy: Snowmass Year = 10^7 sec
- Long term BG extrapolation affected by large uncertainties
 - optimization of collimator settings in MC
 - injection BG not included in data nor MC

→ motivate VXD upgrade → *talk by Katsuro Nakamura*



Integrated dose

◆ SVD dose estimated by dose on diamond sensors: 70 krad in layer-3 mid plane (the most exposed to radiation)

- Dose estimate based on correlation between SVD occupancy and diamonds dose
- Several assumptions and large uncertainty (~ 50%)

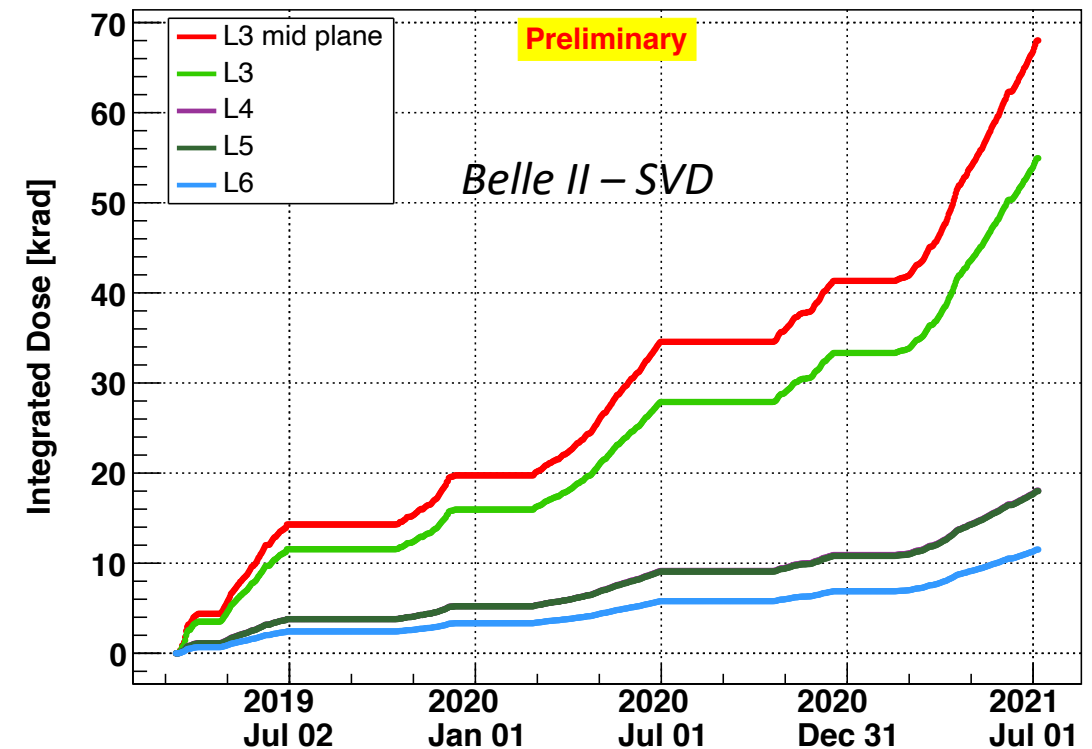
◆ 1-MeV equivalent neutron fluence:
 $\sim 1.6 \times 10^{11} \text{ n}_{\text{eq}}/\text{cm}^2$ in first 2.5 years

- assuming dose/neq fluence ratio
 $= 2.3 \times 10^9 \text{ n}_{\text{eq}}/\text{cm}^2/\text{krad}$ from MC

◆ analysis updated from last year

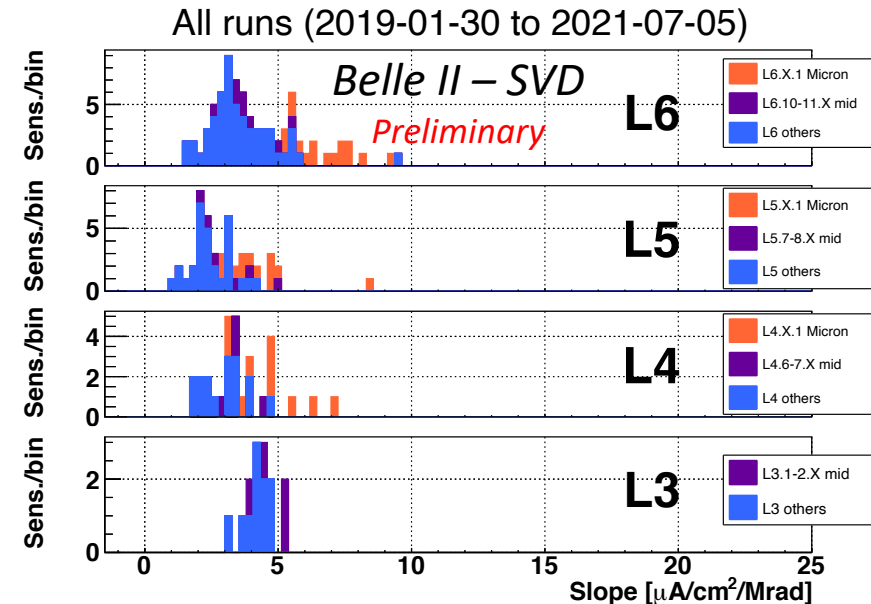
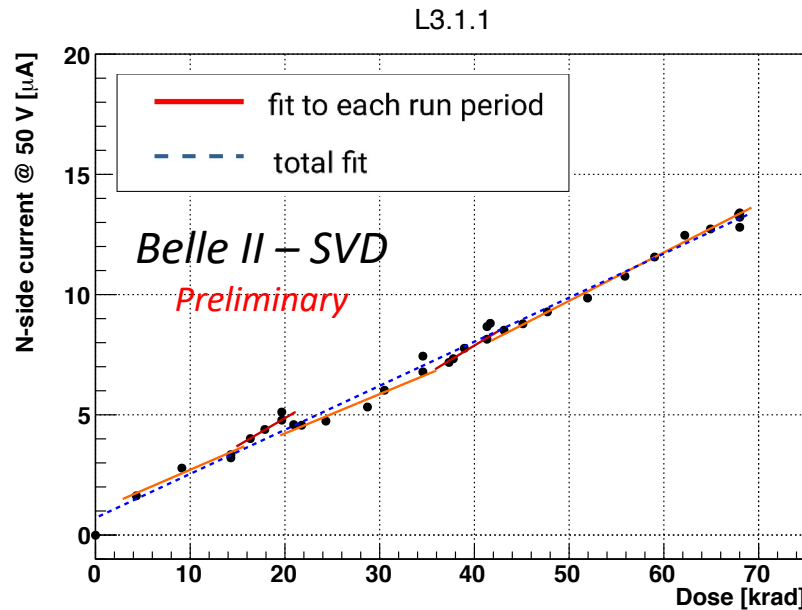
- more suitable trigger used
 - physics trigger \rightarrow Poisson trigger w/o injection veto
 - remove over estimation

Int. dose in SVD - New coeff. (from exp. 12 & 16) + EODB correction (from 14/2102)



Radiation effect on leakage current

- ◆ Good linear correlation between leakage current and estimated dose
 - Slope: 2-5 $\mu\text{A}/\text{cm}^2/\text{Mrad}$ with large variations due to temperature effects and dose spread among sensors in layer (average dose in layer used in estimate)
 - Same order of magnitude as BaBar measurement (1 $\mu\text{A}/\text{cm}^2/\text{Mrad}$ @ 20 °C)
 - [NIMA 729, 615-701, 2013]
 - Strip noise from leakage current is suppressed by short shaping time (50ns) in APV25
 - comparable to the strip-capacitive noise only after 10Mrad irradiation → not problematic for 10 years (2 Mrad)



Radiation effect on strip noise

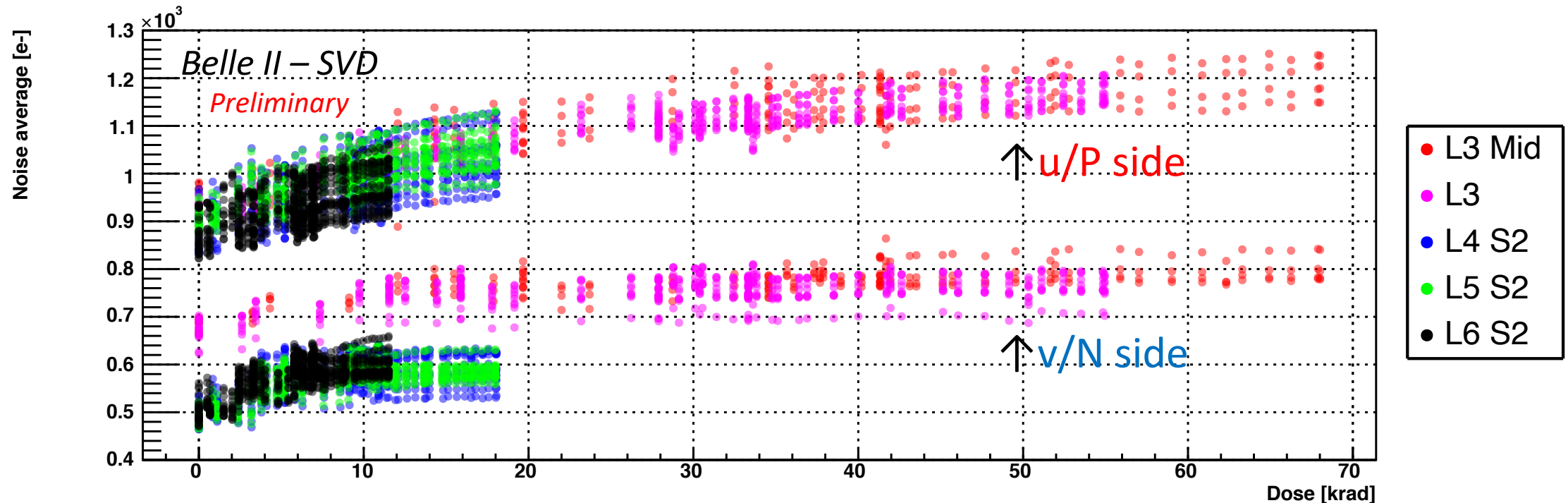
◆ Noise increase of 20-25% in layer-3

- Not affecting performance

- Likely due to radiation effects on sensor surface

 - Non-linear increase due to fixed oxide charges that increase inter-strip capacitance, expected to saturate

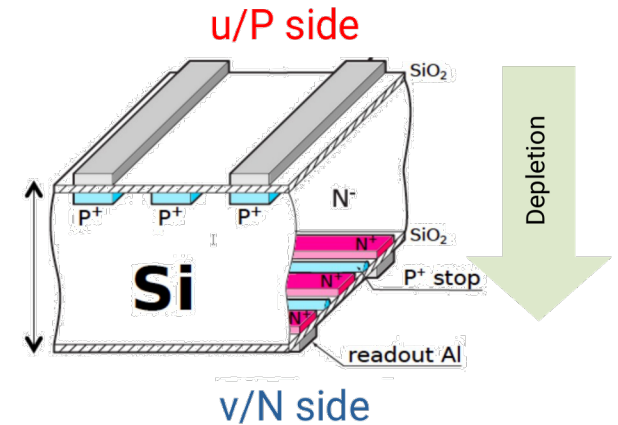
- Saturation seen on v/N side and starting to be seen on u/P



Radiation effect on depletion voltage

◆ v/N side strip noise drops at full depletion

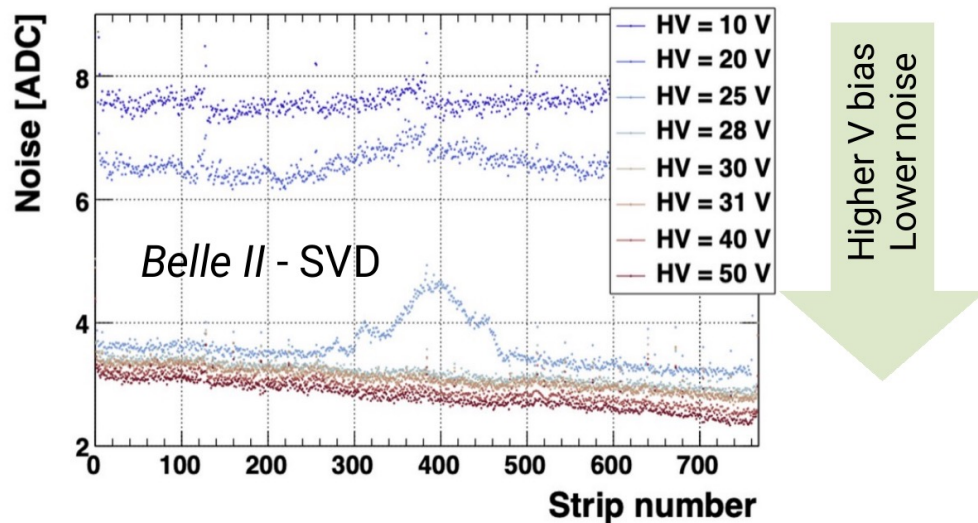
- v/N side insulated only when the n-type bulk is fully depleted
- Over-depletion bias still slightly decrease noise
 - by reducing electron accumulation layer on v/N side surface



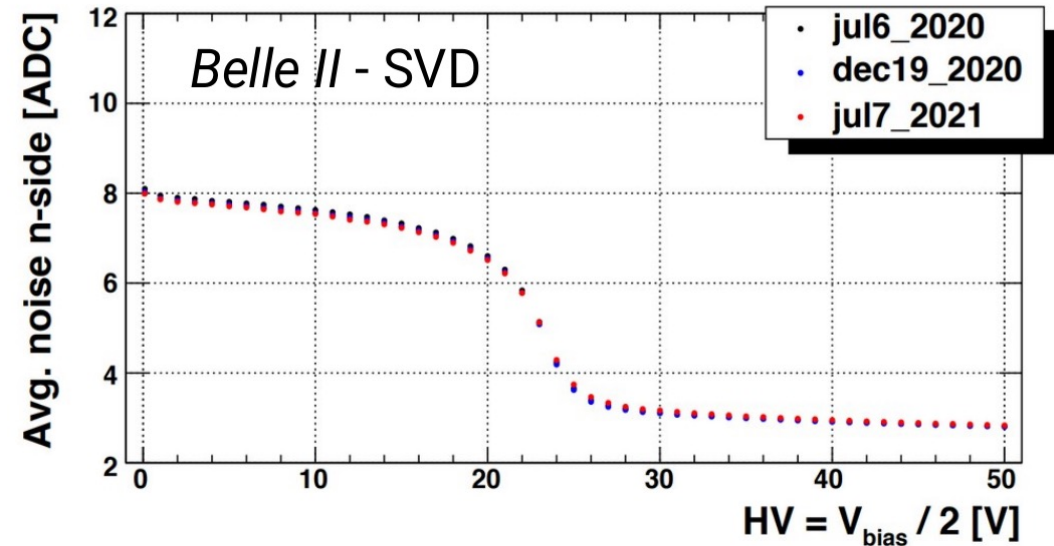
◆ No change in full depletion voltage observed with time

- Consistent with low integrated neutron fluence ($\sim 1.6 \times 10^{11} n_{eq}/cm^2$)

L3.5.1 v/N Side - Strip Noise



L3.5.1 N Side - Noise



Conclusions

- ◆ SVD has been taking data in Belle II since March 2019 smoothly and reliably
- ◆ Excellent performance in agreement with expectations
 - Still some room for improvement in cluster position resolution
- ◆ Seen first effects of radiation damage at the expected level but not affecting performance
- ◆ Ready to cope with increased beam background
 - Reject off-time background using hit-time
 - 3/6-mixed acquisition mode to reduce dead time, data size and occupancy

Thank you!

◆ YSF talks on Belle II SVD:

- “Measurement of the cluster position resolution of the Belle II Silicon Vertex Detector” by Robin Leboucher
- “Simulation of the Belle II Silicon Vertex Detector” by Mateusz Kaleta

Backup

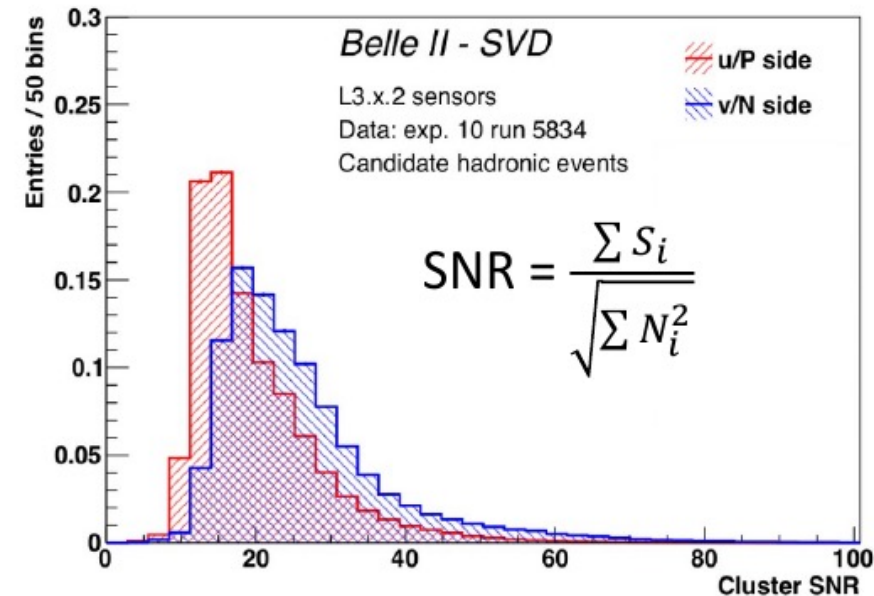
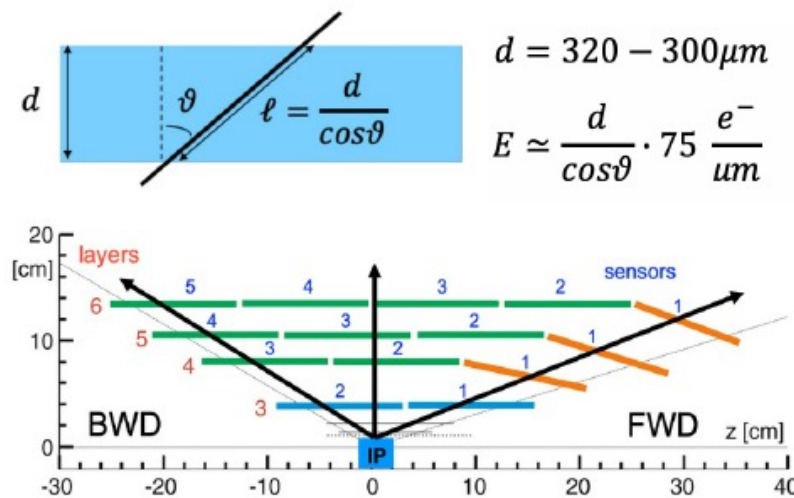
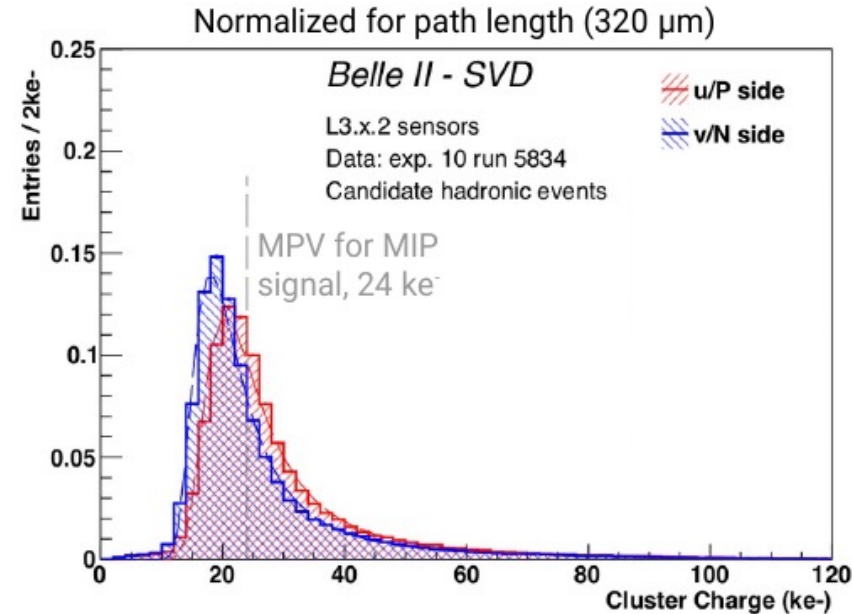
Signal charge and signal-to-noise ratio

◆ Signal charge: normalized for the track path length in silicon

- **u/P side**: agree with MIP considering $\sim 15\%$ uncertainty in APV25 gain calibration
- **v/N side**: 10-30% signal loss due to large pitch and presence of floating strip
 - similar in all sensors

◆ SNR: very good in all sensors (most probable value: 13-30)

- **u/P side**: larger noise due to longer strip length (larger inter-strip capacitance)



Hit-time estimation

- ◆ Neighboring strips over threshold are grouped into ‘cluster’
- ◆ APV samples for strips $a_{strip 0}$, $a_{strip 2}$, $a_{strip 2}$ are summed up:

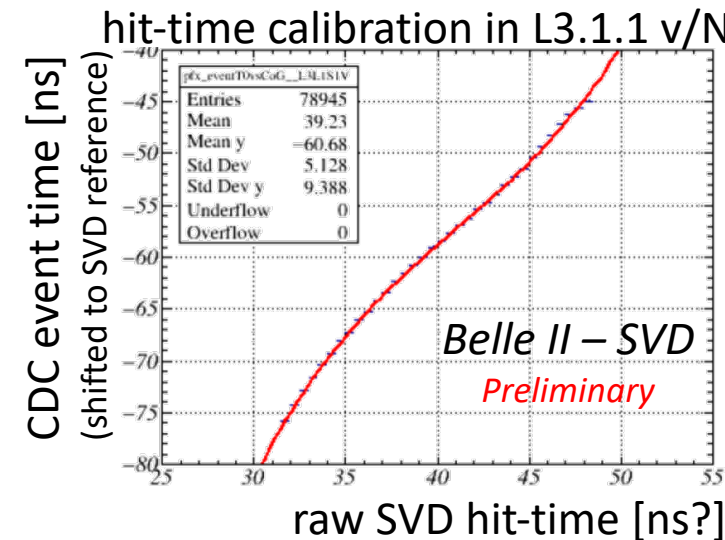
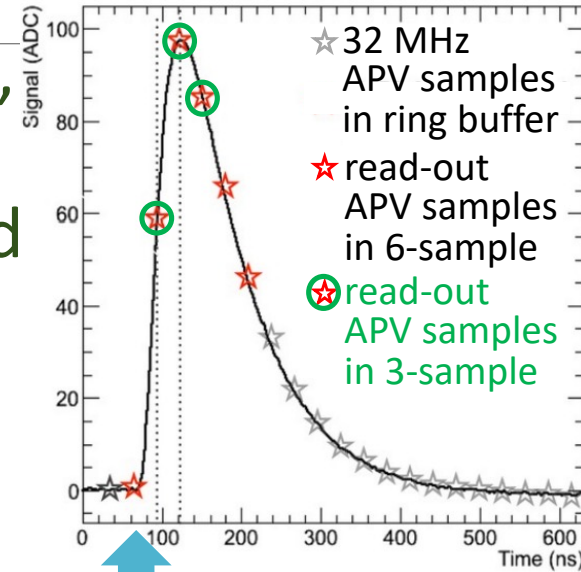
$$a_{cluster i} = \sum_{strip \in cluster} a_{strip i}$$

- ◆ “raw” hit-time is calculated as

$$\frac{\sum_i i \Delta t \cdot a_{cluster i}}{\sum_i a_{cluster i}},$$

where $\Delta t = 31$ ns (clock-cycle of APV25)

- ◆ this “raw” hit-time is calibrated to CDC event time
- ◆ get SVD hit-time



3-sample acquisition mode

◆ efficiency

- emulate 3-sample mode offline using trigger timing information
- based on tracks using CDC, SVD and PXD hits
- > 99.4% for trigger jitter less than 30 ns

◆ efficiency compared to 6-sample

- 3-sample efficiency/6-sample efficiency
- > 99.9% for trigger jitter less than 30 ns
 - almost a whole clock-cycle

